Unitized Semiconductor Devices - Page 1 of 1



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## Inclosure Material:

Metal

## Overall Length:

Between 0.150 inches and 0.260 inches

# **Terminal Length:**

Between 0.500 inches and 0.750 inches

### **Overall Diameter:**

Between 0.335 inches and 0.370 inches

# **Component Name And Quantity:**

2 transistor

### Mounting Method:

Terminal

**Terminal Circle Diameter:** 

0.200 inches

#### Semiconductor Material:

Silicon all transistor

### Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open all transistor and 7.0 emitter to base voltage, static, collector open all transistor and 60.0 collector to emitter voltage/static/base open all transistor

### **Current Rating Per Characteristic:**

500.00 milliamperes source cutoff current all transistor

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Pc bd, adapter plate; all transistor junction pattern arrangement: npn

#### Terminal Type And Quantity:

6 uninsulated wire lead

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

### Fiig:

A110a0